

# The Diamond Beam Monitor for **Luminosity Upgrade of ATLAS**





Summary

Outline of Talk

Motivation

DBM Design **DBM Status** 

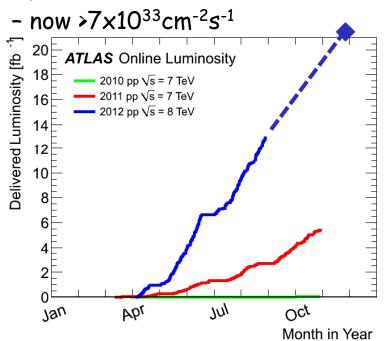
# ATLAS

### Diamond Beam Monitor Motivation

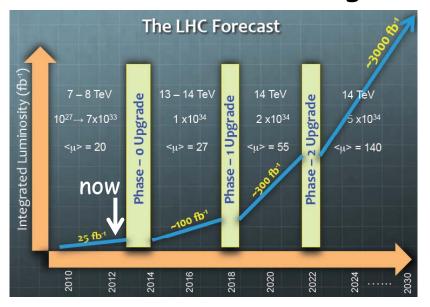


Many precision measurements limited by luminosity determination (e. g. absolute cross section measurements, pp $\rightarrow$ ZX, WZX,...)

Rapid increase in LHC Luminosity



.... And L will continue to grow!



L= 
$$\mu(n_b f_r)/\sigma_{inel}$$

 $\mu$ =average # of inelastic interactions per bunch crossing

$$n_b$$
= # of colliding bunch pairs  
 $f_r$ = machine revolution frequency

LHC parameters  
 $\sigma_{inel}$ = inelastic cross section

Luminosity is a counting issue: requires good segmentation in space or time Problems occur when  $\mu$  can not be reliably measured



### Diamond Beam Monitor Motivation



In order to make a precise determination of the luminosity at the highest instantaneous luminosity & energy we need a detector that is:

radiation hard: accumulate  $2 \times 10^{15} \, n_{eq} / cm^2$  fast: ~nsec resolution, resolve beam bunches stable/reliable: last for ~ "10 years" sensitive to charged particles: prefer min. ionizing

Diamond is a good sensor candidate...



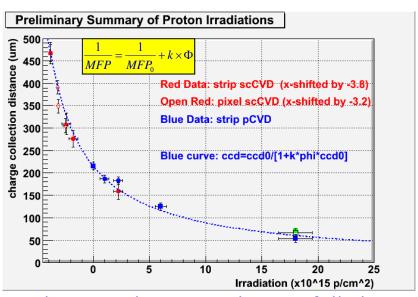
# Chemical Vapor Deposition Diamond

The properties of diamond make it interesting/useful for particle detectors: radiation hard, short collection time, low leakage current, high thermal conductivity

#### Diamond as sensor material

Diditiona as sensor marerial				
Property	Diamond	Silicon		
Band gap [eV] 🗆 Low leakage	5.5	1.12		
Breakdown field [V/cm]	107	3×10 <sup>5</sup>		
Intrinsic resistivity @ R.T. [ $\Omega$ cm]	<b>&gt;</b> 10 <sup>11</sup>	2.3×10 <sup>5</sup>		
Intrinsic carrier density [cm <sup>-3</sup> ]	< 10³	1.5×10 <sup>10</sup>		
Electron mobility [cm²/Vs]	1900	1350		
Hole mobility [cm²/Vs]	2300	480		
Saturation velocity [cm/s]	0.9(e)-1.4(h)x 10 <sup>7</sup>	0.82× 10 <sup>7</sup>		
Density [g/cm³]	3.52	2.33		
Atomic number - Z	6	14		
Dielectric constant - ε 🗆 Low cap	5.7	11.9		
Displacement energy [eV/atom]   Rad hard	43	13-20		
Thermal conductivity [W/m.K]	~2000	150		
Energy to create e-h pair [eV]	13	3.61		
Radiation length [cm]	12.2	9.36		
Interaction length [cm]	24.5	45.5		
Spec. Ionization Loss [MeV/cm]	6.07	3.21		
Aver. Signal Created / 100 μm [e <sub>0</sub> ]    Low Noise, Low signal	3602	8892		
Aver. Signal Created / 0.1 X <sub>0</sub> [e <sub>0</sub> ]	4401	8323		

#### Radiation Studies



Single-crystal CVD & poly CVD fall along the same damage curve Proton damage well understood

At all energies diamond is >3x more radiation tolerant than silicon





# ATLAS Already has 2 Diamond Based Systems

The Beam Condition Monitor (BCM)

The Beam Loss Monitor (BLM)

Both of these systems monitor the LHC beams: can abort the LHC beams useful for determining luminosity



### ATLAS Beam Conditions Monitor

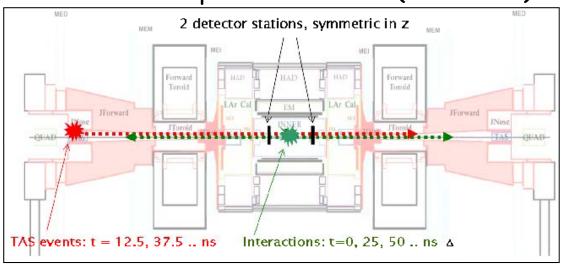


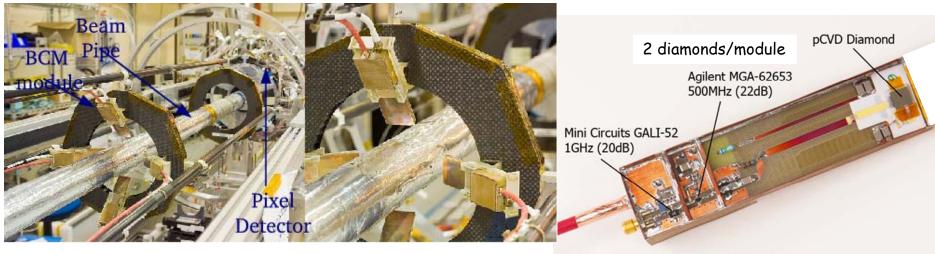
### The ATLAS BCM plays a key role in data taking

luminosity measurement + protection

BCM uses 16 pCVD diamonds ( $1 \times 1 \text{ cm}^2$ )

z=±184 cm r=5.5 cm |n|=4.2



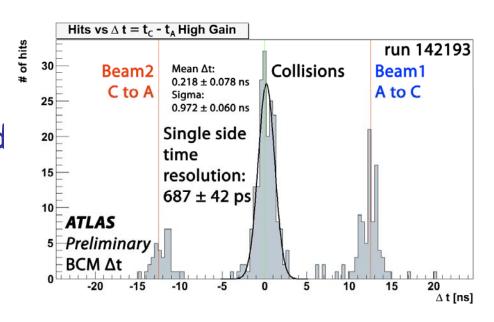




# Data taking with the ATLAS BCM

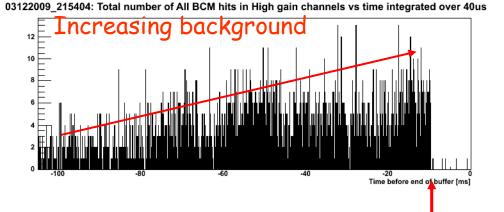


BCM achieved 687ps timing BCM can distinguish real collisions from background



BCM stores a record of 1177+100 orbits

BCM sensitive enough to abort the beams

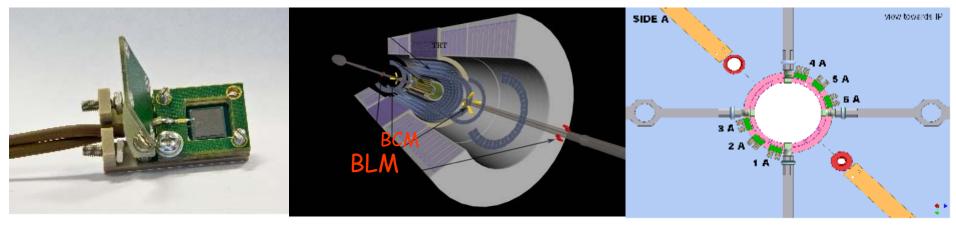




### ATLAS Beam Loss Monitor



BLM uses 12 pCVD diamonds, 6 per side  $z=\pm345$ cm, r=6.5 cm

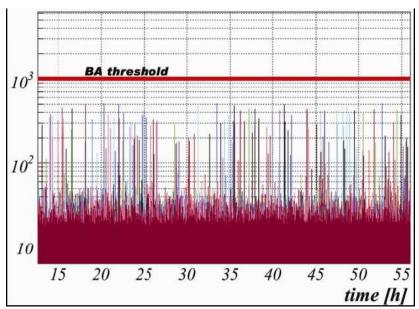


BLM extends the range of the BCM and adds redundancy

BLM running sums give count rate for a given time interval (µs to s)

Both BCM and BLM operate continuously

Aborts beam when necessary

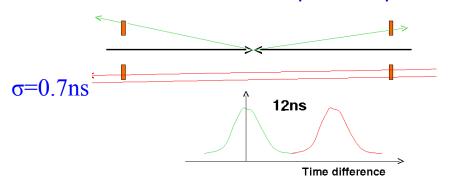


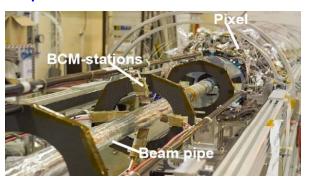


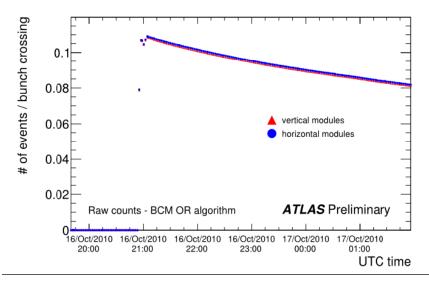


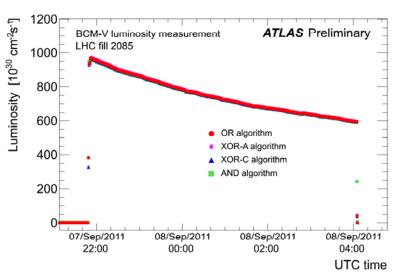
#### Luminosity measurement with the ATLAS diamond BCM

Single Particle Counting: in-time Luminosity & out-of-time Background Flexible: Can run as "OR", "AND", horizontal, vertical







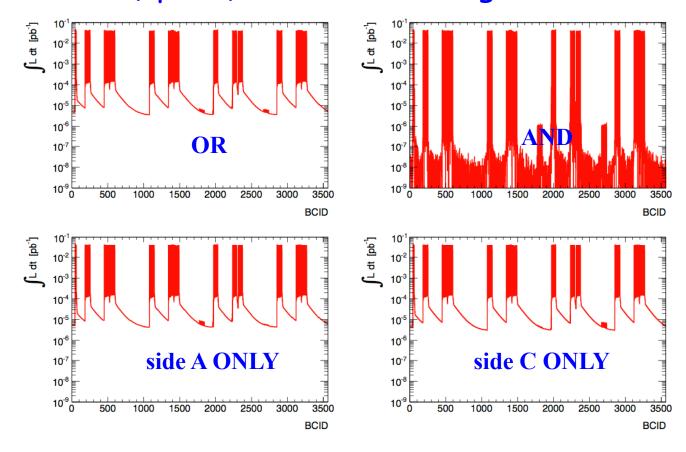


Speed, robustness, stability required for good luminosity measurement





#### The BCM rate (speed) is Beam Crossing ID aware



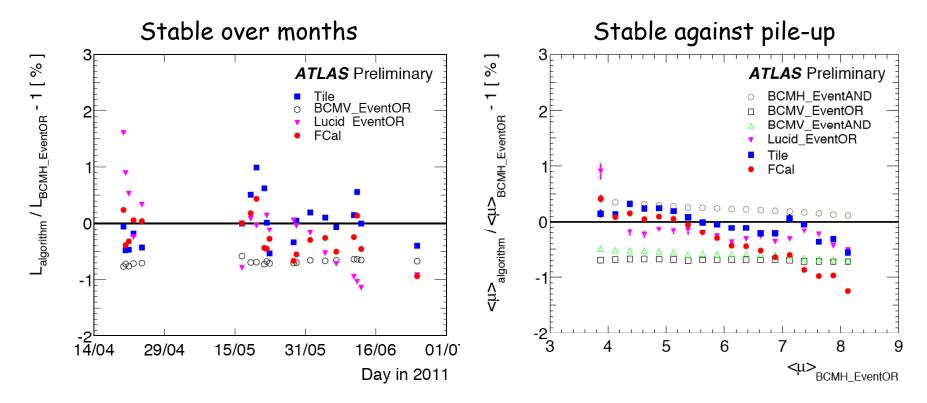
### Provides robust rate measurements, ~ 10<sup>-3</sup> backgrounds





#### Two independent luminosity measurements BCMH & BCMV:

(H=horizontal, V=vertical)



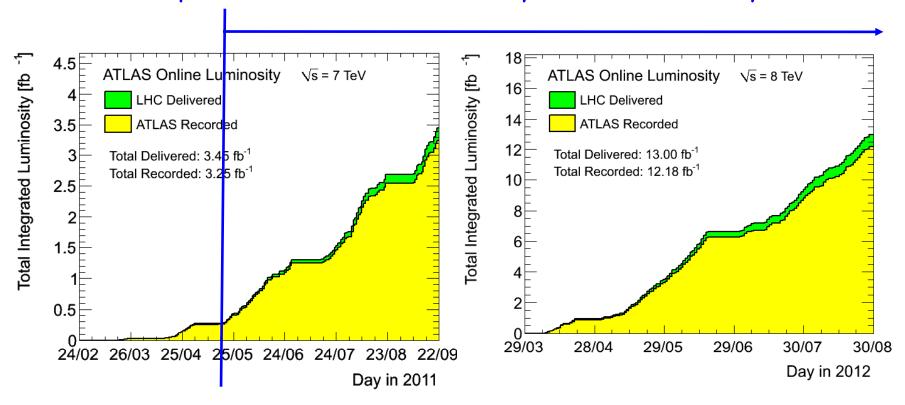
### In 2011 BCM achieved a 1.9% luminosity measurement!

(BUT issues with vDM scans increased systematic error to ~3.5%)





#### The BCM is preferred ATLAS luminosity device since early 2011:



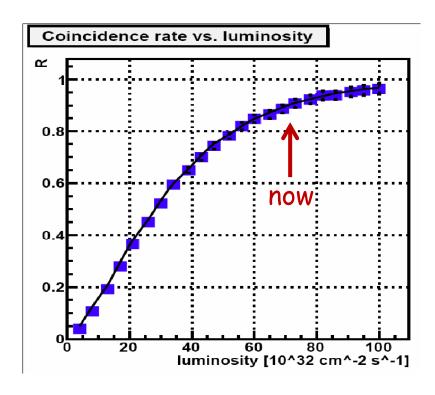
Calibrated in Van der Meer scans
Operates when other systems are not active!



### **DBM** Motivation



The BCM will begin to saturate at  $\sim 10^{34}$  cm<sup>-2</sup>s<sup>-1</sup>:  $\sim$ 



More segmentation  $\rightarrow$  Diamond Beam Monitor (DBM)  $\stackrel{\text{"}}{\cup}$ 



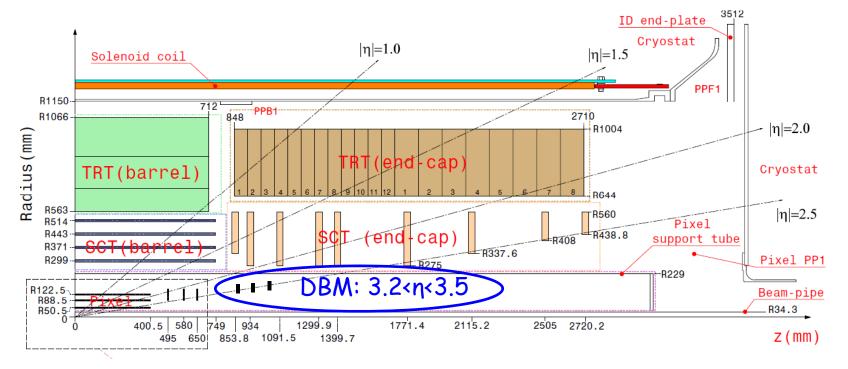
Increase number of channels by  $\sim 10^5$ 





#### Build on success of BCM - pixelate the sensors

- Use IBL diamond pixel demonstrator module use many of the same pieces (FEI4, etc) as IBL to save time/money same segmentation as IBL sensors,  $50 \times 250 \ \mu m^2$
- Install during new Service Quarter Panel (nSQP) replacement
- Four 3-plane stations on each side of the IR



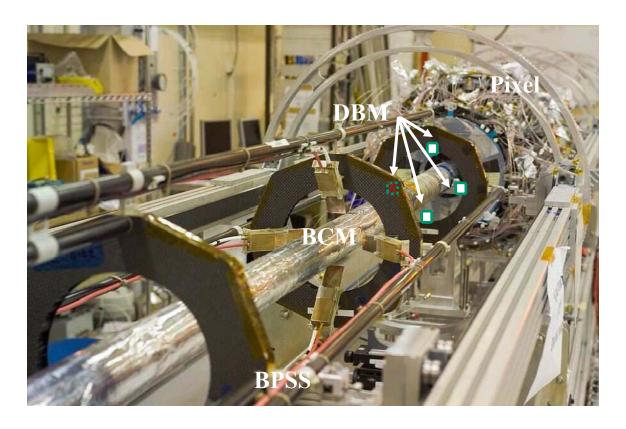




### 24 diamond pixel modules arranged in 8 telescopes provide

- Bunch by bunch luminosity monitoring
- Bunch by bunch beam spot monitoring

#### Installation in summer 2013





# The ATLAS DBM Specs and Collaboration



#### Specs:

- Bunch by bunch luminosity monitoring (<1% stats/sec)</li>
- Bunch by bunch beam spot monitoring (unbiased sample, ~ 1cm)

Bonn CERN Göttingen Ljubljana N. Mexico OhioSt Toronto

















# The ATLAS DBM Tracking Simulation



#### Simulate DBM to find best orientation and resolution

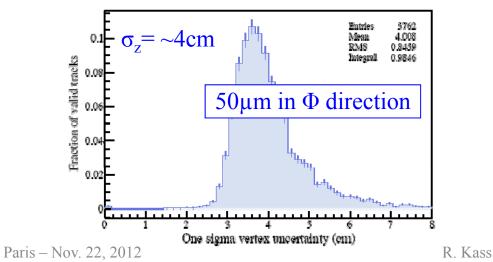
Focus on z vertex resolution (momentum resolution bad)

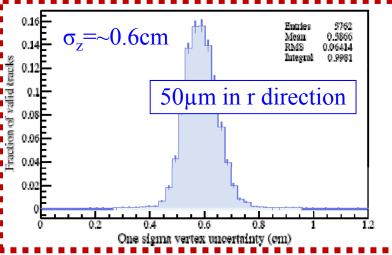
3 layers of tracking with 50 x 250  $\mu$ m<sup>2</sup> pixel cell

Two choices of pixel orientation, pick the one that gives

the best z-vertex resolution



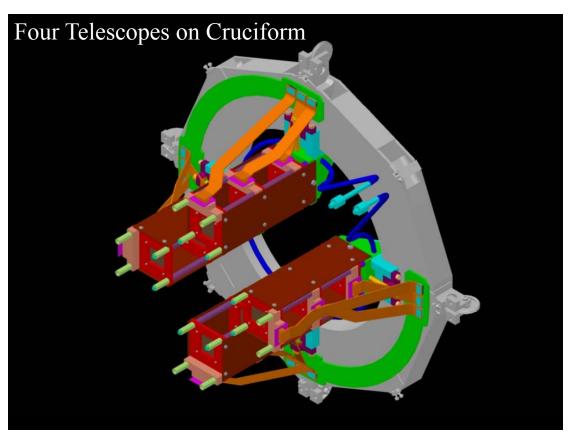


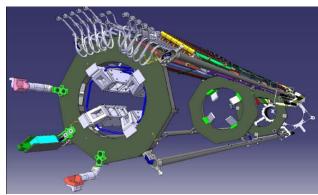


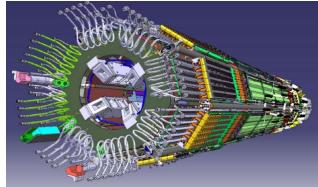




Mechanics finalized – use as many IBL parts as possible Mechanical simulations complete  $\rightarrow$  Al, AlN, Peek



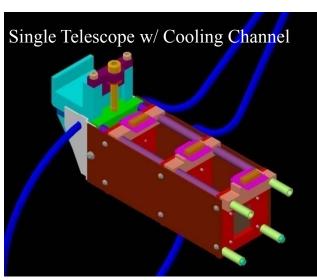


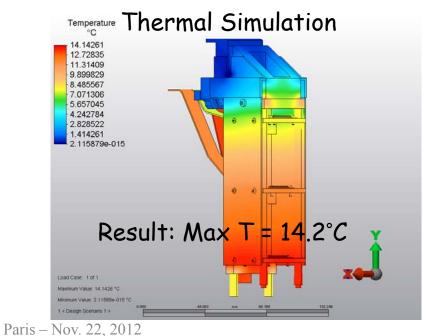


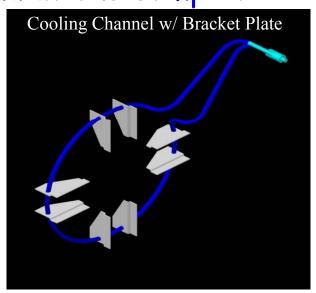


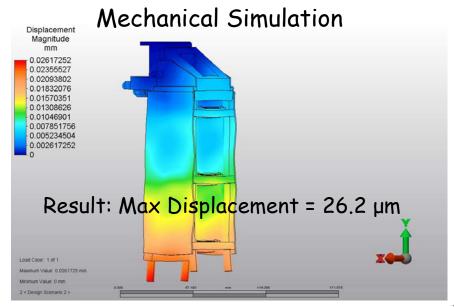


### Thermal & mechanical simulations complete











## DBM Diamond Sensor Plan



### Diamond Sensors for DBM:

Type: polycrystalline CVD diamond Charge collection distance > 250 µm

(as measured with Sr90 source)

Size:  $21 \times 18 \text{ mm}^2$ ,  $525 \pm 25 \mu\text{m}$  thickness

Number: 24 for DBM modules + spares

5 for Irradiation studies



21 x 18 mm<sup>2</sup> pCVD diamond

# Two diamond suppliers involved:

Diamond Detectors Limited (DDL)/E6 (UK based) II-VI (US based)



# How much Diamond is in the DBM?



About as much as in the diamond Richard Burton bought for Liz Taylor in 1969

~ 70 carats

Auctioned in 1978 for \$5M

http://en.wikipedia.org/wiki/Taylor-Burton\_Diamond

Each DBM sensor is ~ 3.2 carats (1 carat= 200 mg)

Entire DBM: 24 sensors

~ 76 carats!

Price of all DBM diamond < \$150k





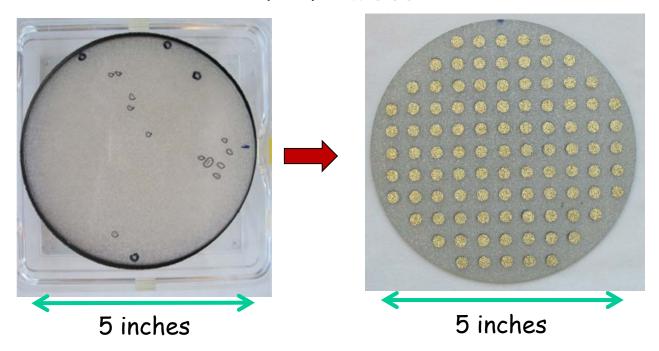
# DBM Diamond Sensor Qualification



At OSU we put conducting contacts ("gold dots") on the diamond & measure the charge collection properties in the region of each dot.

Use Sr90 as a source of particles for charge collection measurements

#### A wafer from DDL

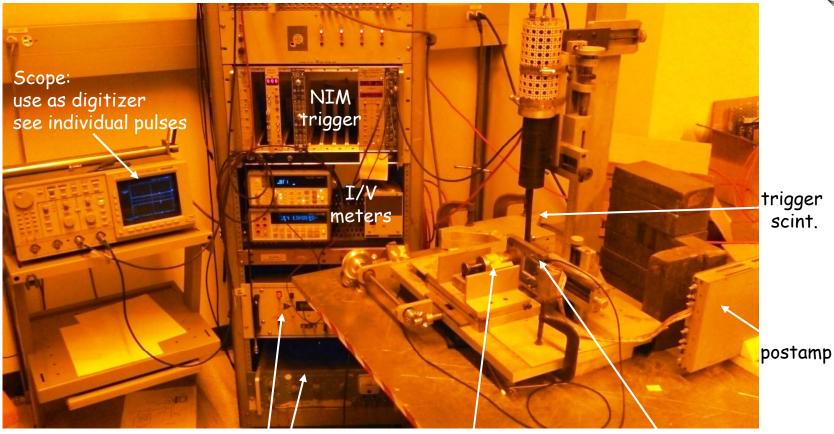


We also make a map of the current draw as we measure CCD Good regions have  $I < 5 \, \text{nA}$  at 1000V in air



# CCD measurement with Sr90 @ OSU

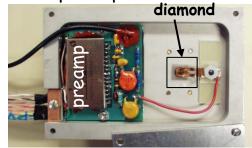


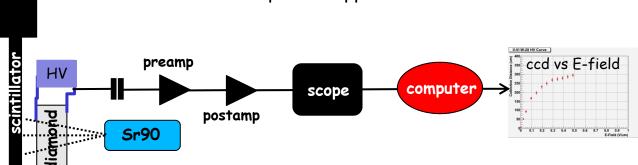


power supplies

1mC Sr90 source

diamond holder and preamp

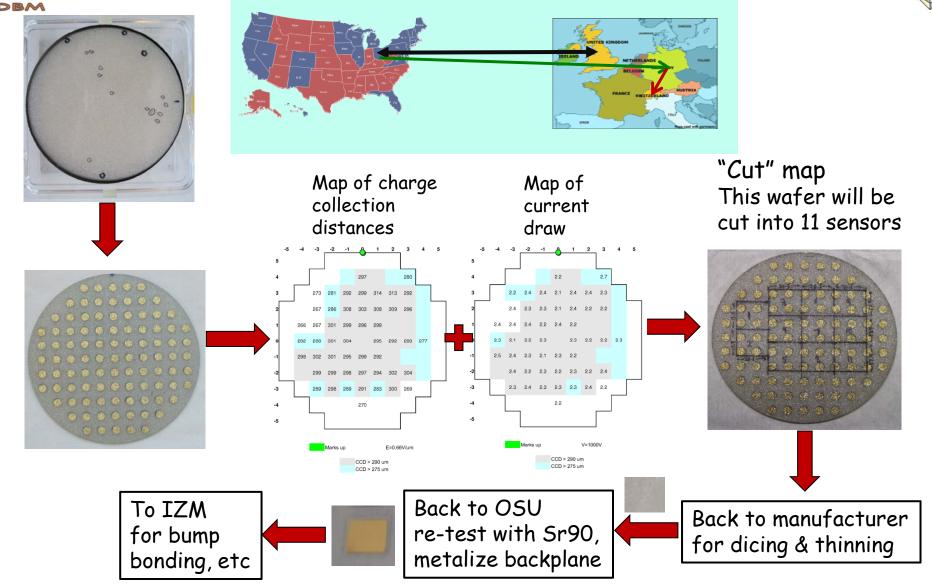






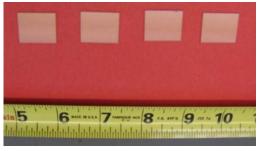
# DBM Diamond Sensor Qualification



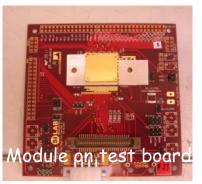


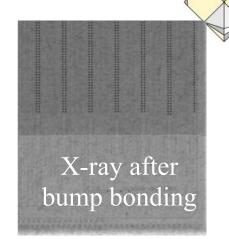


### DBM Module Production





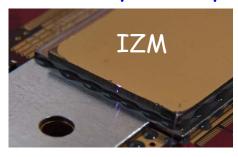


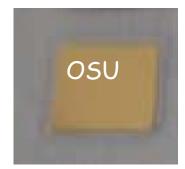


HV Problems with first modules from IZM

Backside metalization goes to the edge of diamond and breaks down Fixed by changing back metalization procedure

- no longer performed by IZM, performed at Ohio State





14 sensors currently at IZM put pixel pattern on diamond bump bond diamond to FEI4



#### DBM Module Testbeam

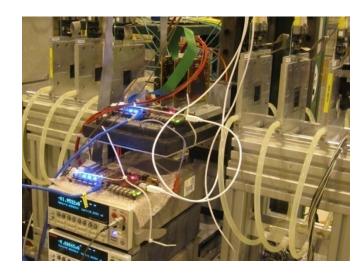


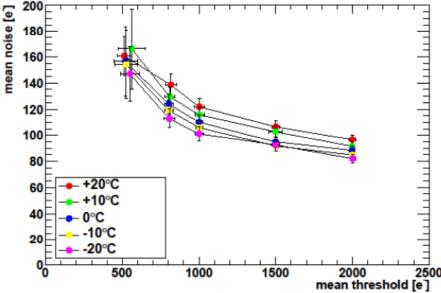
- Three Testbeam campaigns
  - Oct 11, Mar 12, Jun 12
- Learning about FE-I4 performance
  - Calibration/tunings for low threshold performance

#### What is possible?

x = October 2011 DBM Test Beam

			Λ Ο	MODOL ZOTT D	DIVI TEST DEATH
Threshold Gain	500e	800e	1000e	1500e	2000e
8ToT@3ke	х	x			
8ToT@5ke	×	×		×	
8ToT@8ke	х	x	Green Valley"	х	х
8ToT@10ke		х	They w		
8ToT@15ke					







#### DBM Module Testbeam

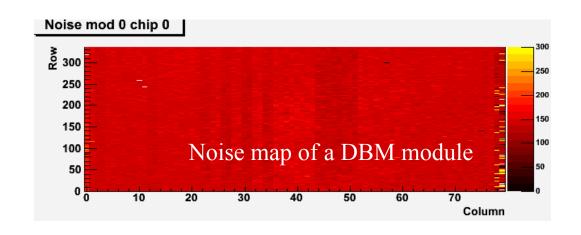


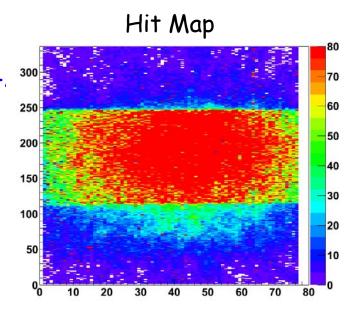
#### Prototype Modules Tested:

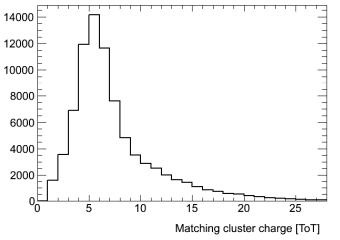
- 21mmx 18mm pCVD diamond w/FE-I4.
- $336 \times 80 = 26880$  channels
- $50 \times 250 \, \mu \text{m}^2 \, \text{pixel cell}$

#### Results

- Noise map uniform
- Efficiency >95%









#### DBM Module Testbeam

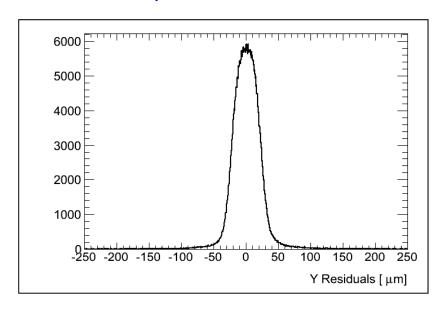


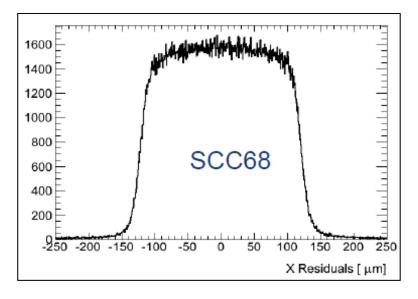
#### Prototype Modules Tested:

- 21mmx 18mm pCVD diamond w/FE-I4A
- $336 \times 80 = 26880$  channels
- $50 \times 250 \, \mu \text{m}^2$  pixel cell

#### Results

Spatial resolution looks digital







# OSU's DBM Hitbus Chip Overview

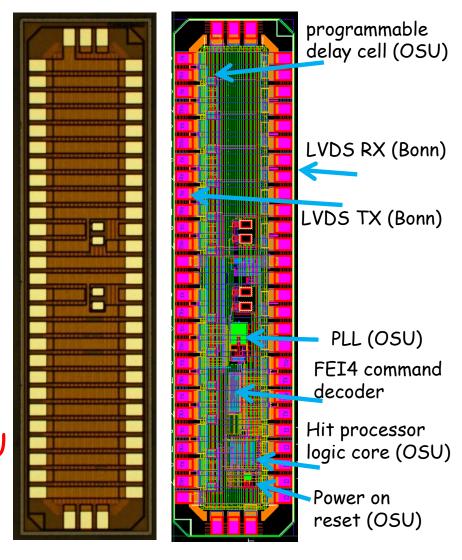


ASIC developed to provide L1A trigger for the DBM by using the FEI4 Hitbus outputs

Each DBM hitbus chip services 2 telescopes so 4 chips needed for entire DBM

Use IBM 130nm 8RF CMOS Size: 4.59 mm × 1.06mm

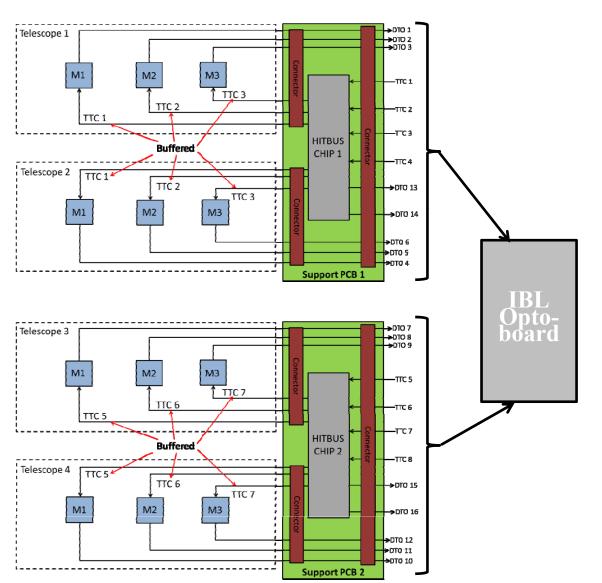
Incorporates shared circuit blocks from FEI4 collaboration & custom blocks designed at OSU



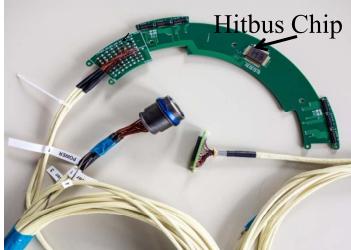


# Half DBM System Block Diagram





### 2 Support PCBs/side





# Hitbus Chip Irradiation



31

# Need to certify that Hitbus Chip is rad hard

Irradiated 2 Hitbus chips to  $4.3 \times 10^{15} \text{ p/cm}^2 (115 \text{ Mrad})$ 

Used 24 GeV proton beam at CERN

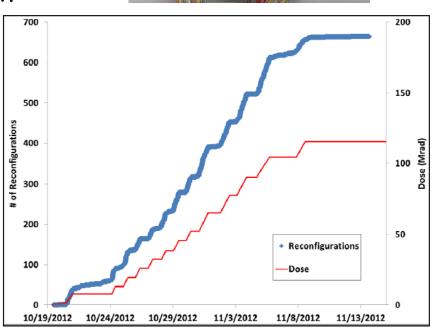
Both chips survived
Slight increase in supply current consumption

All functionality active during irradiation

Test system checked for SEU in the received data

Looked for flipped bits in SEU latches change of Hitbus desired function

Reconfigured the chip if error detected Only 664 reconfiguration events needed (for both chips)

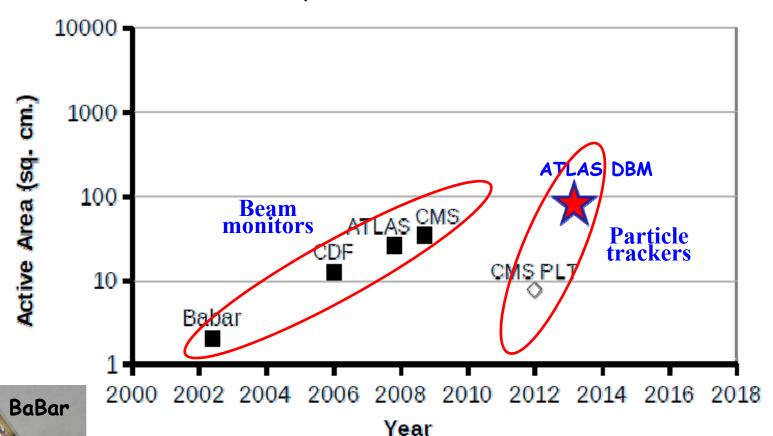




# DBM and Other Diamond Projects



DBM has  $\sim 6.25 \times 10^5$  channels (DELPHI silicon pixel detector  $\sim 12 \times 10^5$  channels)



BaBar beam monitor: two pCVD diamonds 1 cm x 1 cm x 500 µm



# Summary



- Construction of the largest diamond pixel tracker underway
- Satisfies constraints for precision luminosity measurement
  - Bunch by bunch measurement
  - Background separation uses z resolution
- Should be robust against
  - Pile-up
  - Radiation damage

ATLAS Diamond Beam Monitor TDR: ATU-DBM-001





# Backup Slides

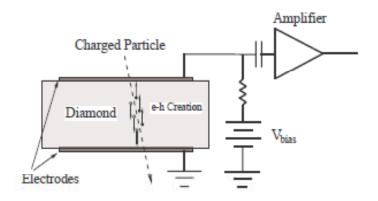




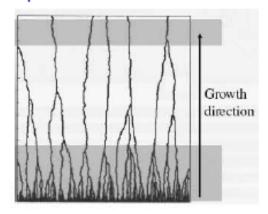
# Charge Collection in CVD Diamond

#### Detectors Constructed with Diamond:

Signal formation



pCVD Schematic Side View



- $\bullet$  d= $(\mu_e \tau_e + \mu_h \tau_h)E$  where d = collection distance = ave. dist. e-h pair move apart
- $\begin{array}{ll} \blacklozenge \ \, \mathrm{d} = \mu \mathsf{E} \tau = \mathsf{V} \tau \\ & \text{with} \quad \mu = \mu_e + \mu_h \, \to \, \mathsf{V} = \mu \, \, \mathsf{E} \\ & \text{and} \quad \tau = \frac{\mu_e \tau_e + \mu_h \tau_h}{\mu_e + \mu_h} \end{array}$
- lacktriangledown Q= $rac{d}{t}$ Q $_0$  ightarrow for large charge need good collection distance must maximize  $\mu$  and au

R. Kass

 $\blacklozenge I = Q_0 \frac{v}{d}$ 





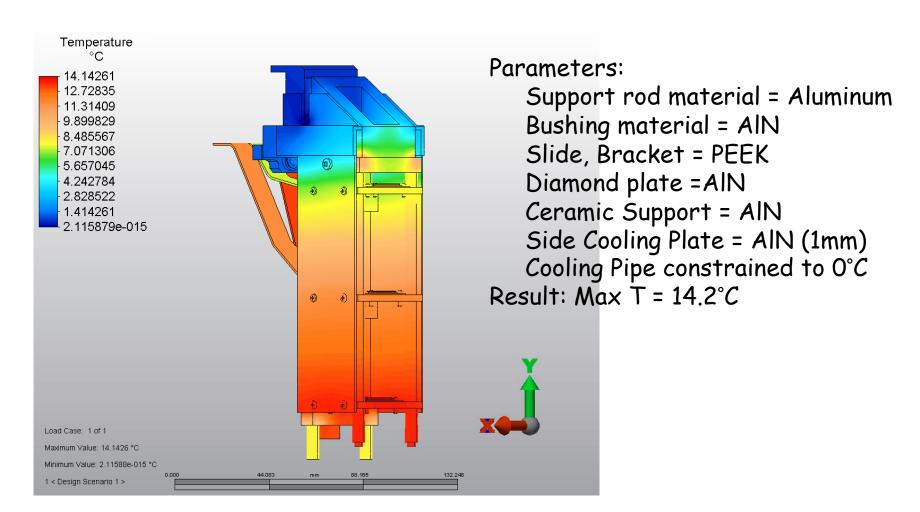


Property	Specifications
Sensor size	21mm x 18mm (active area 20mm x 16.8mm)
Sensor Thickness	400-500 microns
Minimum charge collection distance	200 microns
Minimum average charge	7200 electrons
Minimum collection distance/ charge after 2x10 <sup>15</sup> cm <sup>-2</sup>	100 microns/3600 electrons
Minimum signal/threshold after 2x10 <sup>15</sup> cm <sup>-2</sup>	3
Maximum operating voltage	1000 V
Maximum total leakage current (@1000 V)	100 nA





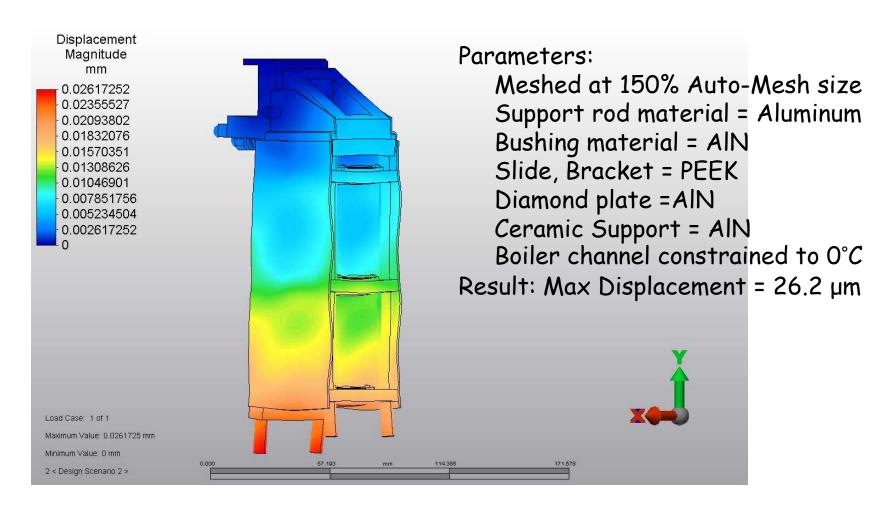
• Cooling simulations for DBM telescope  $w/3 \times 1W + AIN$  side plate







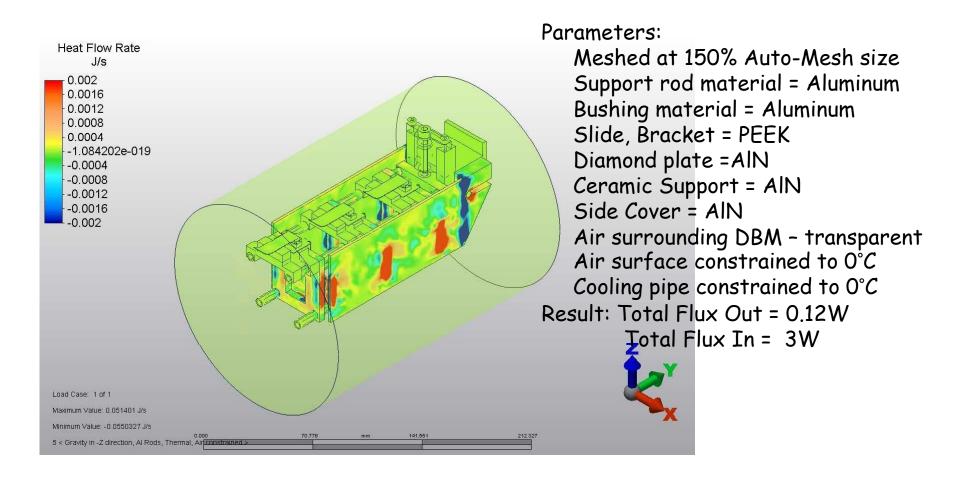
• Mechanical simulations for DBM telescope  $w/3 \times 1W + AIN$  side plate







Heat Flux through a DBM telescope w/3 x 1W





### Radiation Damage - Basics



Radiation induced effect	Diamond	Operational consequence	Silicon	Operational consequence
Lockess summent	small &	nono	I/V = αΦ	Heating
Leakage current	decreases	none	$a \sim 4 \times 10^{-17} \text{ A/cm}$	Thermal runaway
Space charge	~ none	none	$\Delta N_{eff} pprox$ - $eta \Phi$	Increase of full
			$\beta \sim 0.015 \text{ cm}^{-1}$	depletion voltage
Charge trapping	Voc	Charge loss	$1/\tau_{eff} = \beta\Phi$	Charge loss
	Yes	Polarization	$\beta \sim 5-7 \times 10^{-16} \text{ cm}^2/\text{ns}$	Polarization

#### Charge trapping the only relevant radiation damage effect

NIEL scaling questionable a priori

 $E_{qap}$  in diamond 5 times larger than in Si

Many processes freeze out

Typical emission times order of months

Like Si at 300/5 = 60 K - Boltzmann factor

A rich source of effects and (experimental) surprises!

$$\frac{1}{\tau_{eff}} = \sum_{t} N_{t} (1 - P_{t}) \sigma_{t} v_{th}$$



# Summary of RD42 Test Beam Results for CVD Diamond



Particle	Energy	Relative k
р	24GeV	1.0
	800MeV	1.6-1.8
	70MeV	2.5-2.8
	25MeV	4.0-5.0
π	200MeV	2.5-3.0

k is relative damage constant

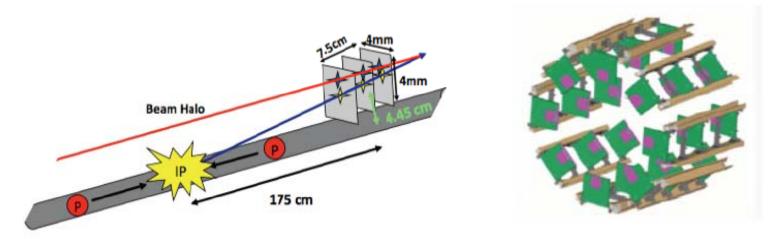


# CMS Pixel Luminosity Telescope



#### Dedicated stand-alone luminosity monitor for CMS

- · High precision bunch-by-bunch luminosity
- · Array of 3-plane telescopes each end of CMS
- Single-crystal diamond pixel sensors
- · Measure bunch-by-bunch 3-fold coincidence rate
- Pixel readout for tracking and diagnostics



Install in CMS in 2013-2014 shutdown